

# N-CHANNEL MOS FIELD EFFECT POWER TRANSISTOR

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## 2SK785

**DESCRIPTION** The 2SK785 is N-channel MOS Field Effect Power Transistor designed for switching power supplies DC-DC converters.

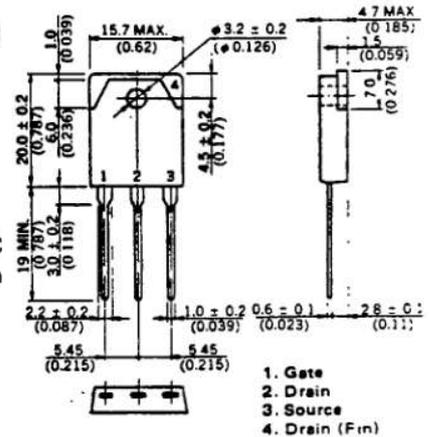
- FEATURES**
- Suitable for switching power supplies, actuator controls, and pulse circuits.
  - Low  $R_{DS(on)}$
  - No second breakdown

**ABSOLUTE MAXIMUM RATINGS**

<b>Maximum Temperatures</b>	
Storage Temperature . . . . .	-55 to +150 °C
Channel Temperature . . . . .	150 °C Maximum
<b>Maximum Power Dissipation (<math>T_C = 25 °C</math>)</b>	
Total Power Dissipation . . . . .	150 W
<b>Maximum Voltages and Currents (<math>T_a = 25 °C</math>)</b>	
$V_{DSS}$ Drain to Source Voltage . . . . .	500 V
$V_{GSS}$ Gate to Source Voltage . . . . .	±20 V
$I_{D(DC)}$ Drain Current (DC) . . . . .	±20 A
$I_{D(pulse)}$ Drain Current (pulse)* . . . . .	±80 A

\*  $PW \leq 300 \mu s$ , Duty Cycle  $\leq 2\%$

**PACKAGE DIMENSIONS**  
in millimeters (inches)



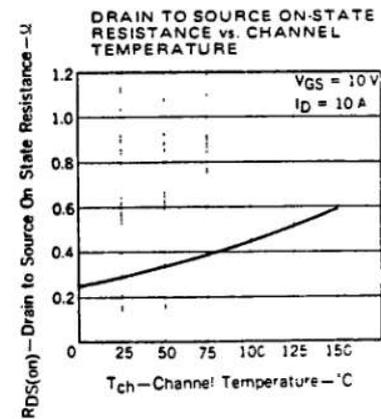
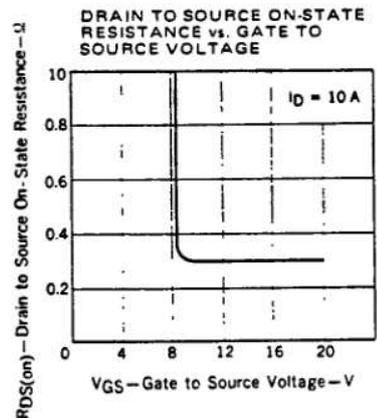
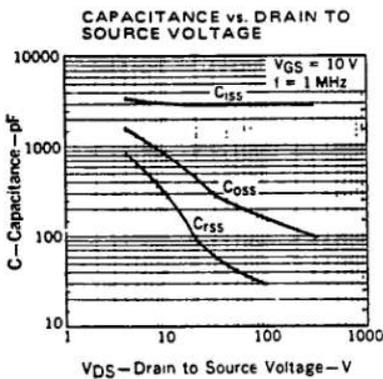
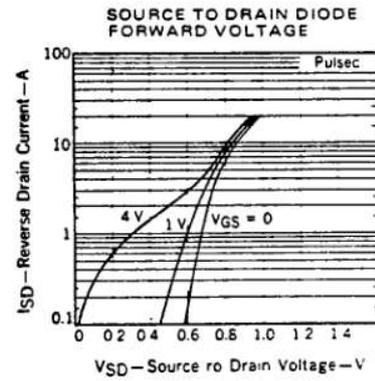
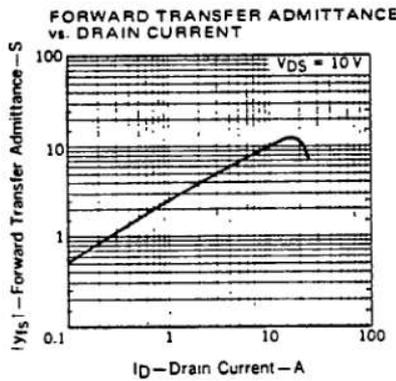
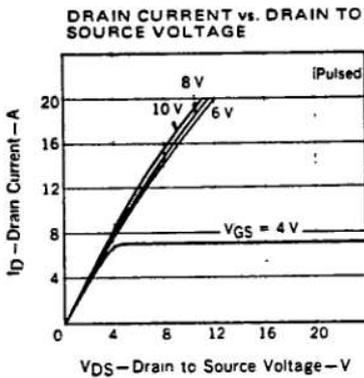
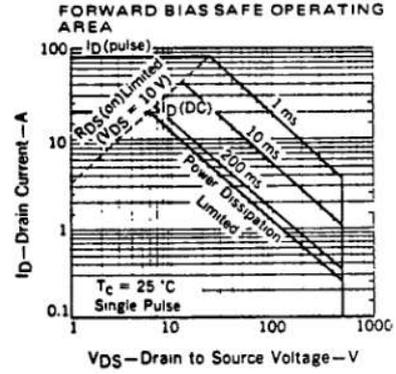
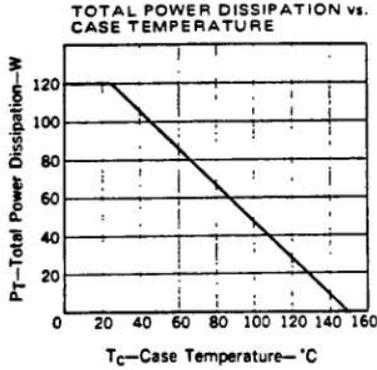
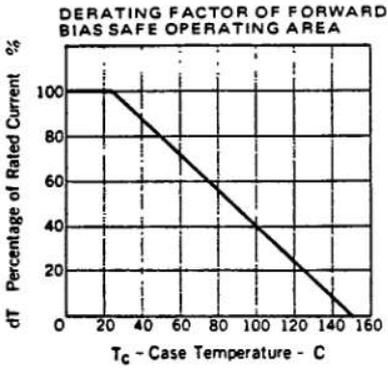
**ELECTRICAL CHARACTERISTICS ( $T_a = 25 °C$ )**

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
$I_{DSS}$	Drain Leakage Current			100	$\mu A$	$V_{DS} = 500 V, V_{GS} = 0$
$I_{GSS}$	Gate to Source Leakage Current			±100	nA	$V_{GS} = \pm 20 V, V_{DS} = 0$
$V_{GS(off)}$	Gate to Source Cutoff Voltage	1.5		3.5	V	$V_{DS} = 10 V, I_D = 1 mA$
$-Y_{fs}^1$	Forward Transfer Admittance	9.0			S	$V_{DS} = 10 V, I_D = 10 A$
$R_{DS(on)}$	Drain to Source On-State Resistance		0.3	0.4	$\Omega$	$V_{GS} = 10 V, I_D = 10 A$
$C_{iss}$	Input Capacitance		3000		pF	$V_{DS} = 10 V, V_{GS} = 0, f = 1 MHz$
$C_{oss}$	Output Capacitance		900		pF	
$C_{rss}$	Reverse Transfer Capacitance		350		pF	
$t_{d(on)}$	Turn-On Delay Time		45		ns	
$t_r$	Rise Time		60		ns	$I_D = 10 A, V_{CC} \approx 150 V$ $V_{GS(on)} = 10 V$ $R_L = 15 \Omega$ $R_{in} = 10 \Omega$
$t_{d(off)}$	Turn-Off Delay Time		100		ns	
$t_f$	Fall Time		80		ns	

NEC cannot assume any responsibility for any circuits shown or represent that they are free from patent infringement

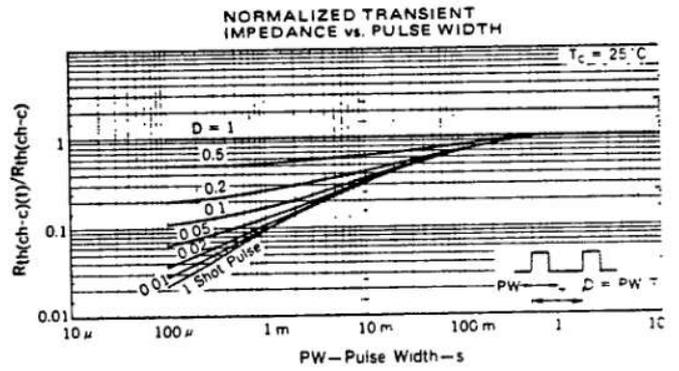
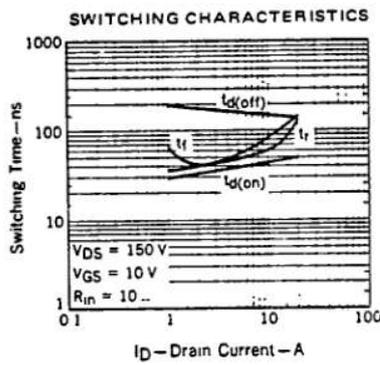
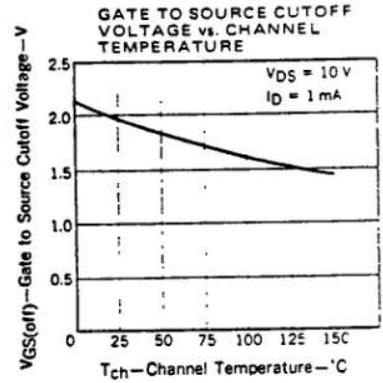
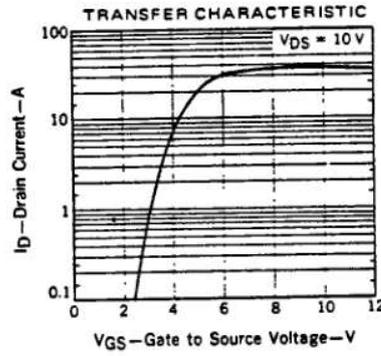
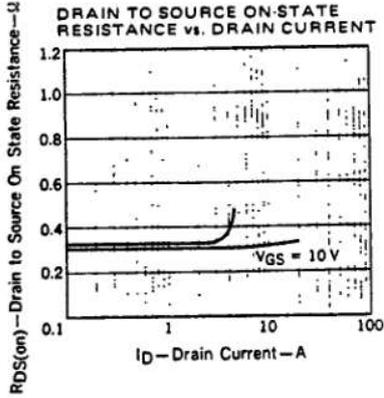
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TYPICAL CHARACTERISTICS (T<sub>a</sub> = 25 °C)



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**SWITCHING TIME TEST CIRCUIT**

